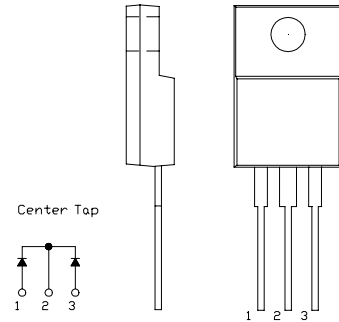


**6A 100V**
**SBD Type : FCH06A10**

OUTLINE DRAWING

**構造** : ショットキーバリアダイオード(SBD)  
 Construction: Schottky barrier Diode  
 カソード コモン型

**用途** : 高周波整流用  
 Application : High Frequency Rectification


**最大定格 / Maximum Ratings**

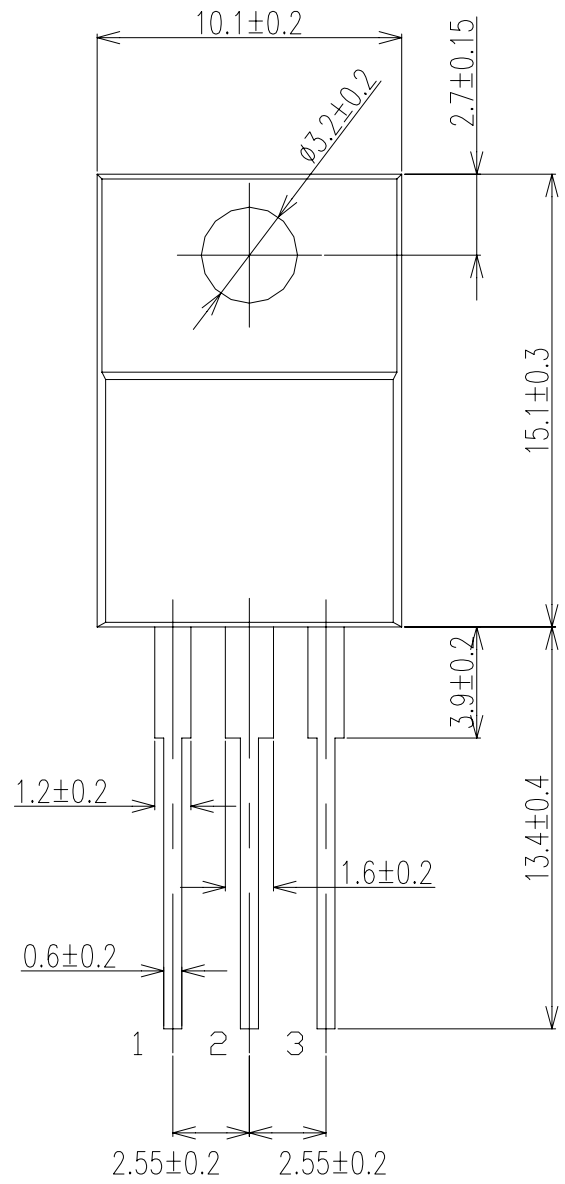
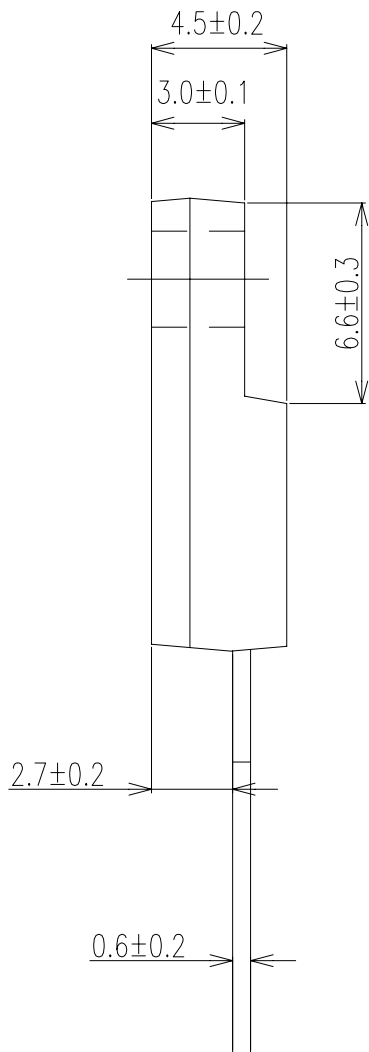
Approx Net Weight:1.75g

Rating	Symbol	FCH06A10		Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	$V_{RRM}$	100		V
平均整流電流 Average Rectified Output Current	$I_O$	6	$T_c=121$ 50 Hz, 正弦全波通電、抵抗負荷 Full Sine Wave Resistive Load	A
実効順電流 RMS Forward Current	$I_{F(RMS)}$	6.6		A
サージ順電流 Surge Forward Current	$I_{FSM}$	80	50 Hz 正弦全波, 1サイクル, 非くり返し Full Sine Wave, 1cycle, Non-repetitive	A
動作接合温度範囲 Operating Junction Temperature Range	$T_{jw}$	- 40 ~ + 150		
保存温度範囲 Storage Temperature Range	$T_{stg}$	- 40 ~ + 150		
締め付けトルク Mounting torque	$F_{tor}$	0.5	推奨値 Recommended value	N·m

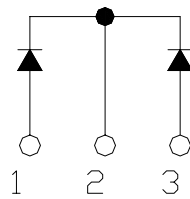
**電氣的・熱的特性 / Electrical · Thermal Characteristics**

Characteristics	Symbol	Conditions	Min	Typ	Max.	Unit
ピーク逆電流 Peak Reverse Current	$I_{RM}$	$T_j=25$ , $V_{RM}=V_{RRM}$ per Diode	-	-	1	mA
ピーク順電圧 Peak Forward Voltage	$V_{FM}$	$T_j=25$ , $I_{FM}= 3A$ per Diode	-	-	0.85	V
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合部・ケース間 Junction to Case	-	-	5	/W
	$R_{th(c-f)}$	ケース・フィン間 Case to Fin	-	-	1.5	

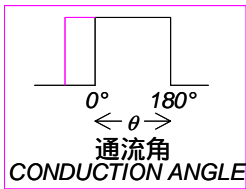
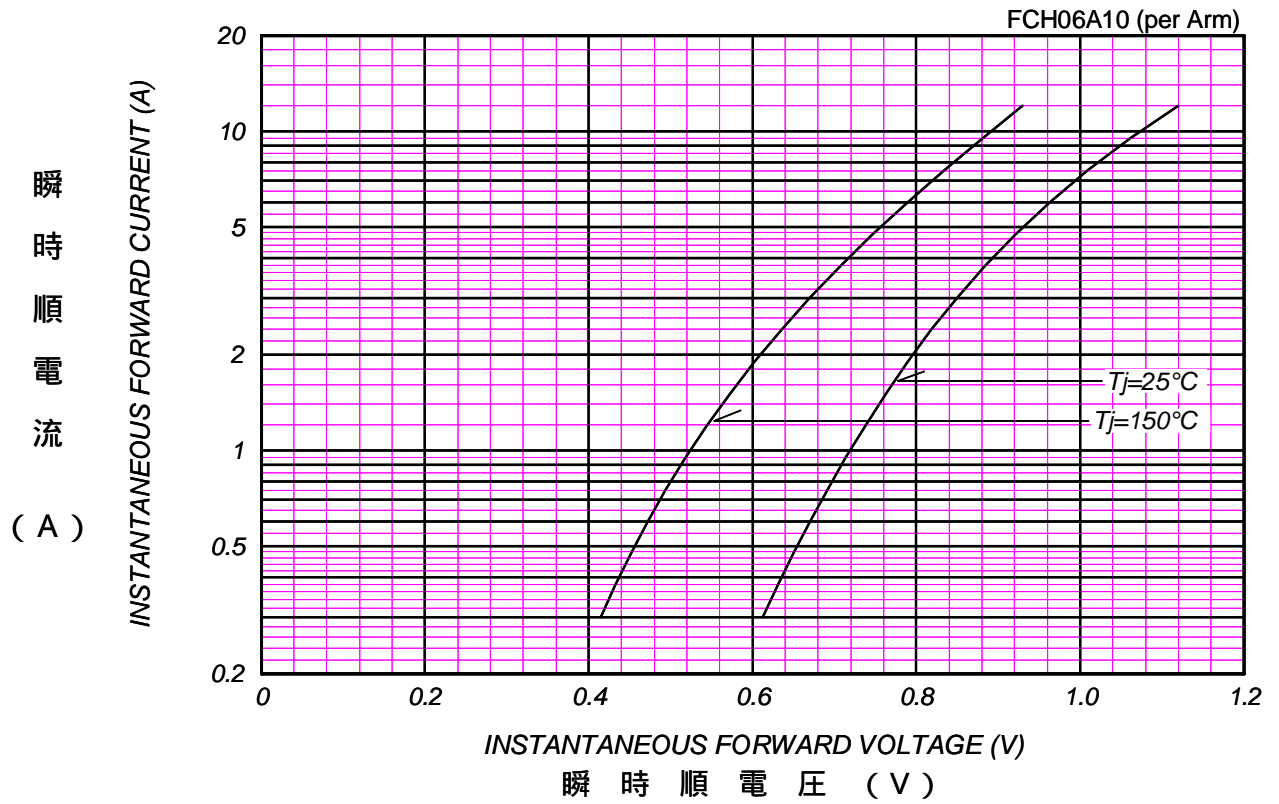
FCH\_A\_外形図 (mm)



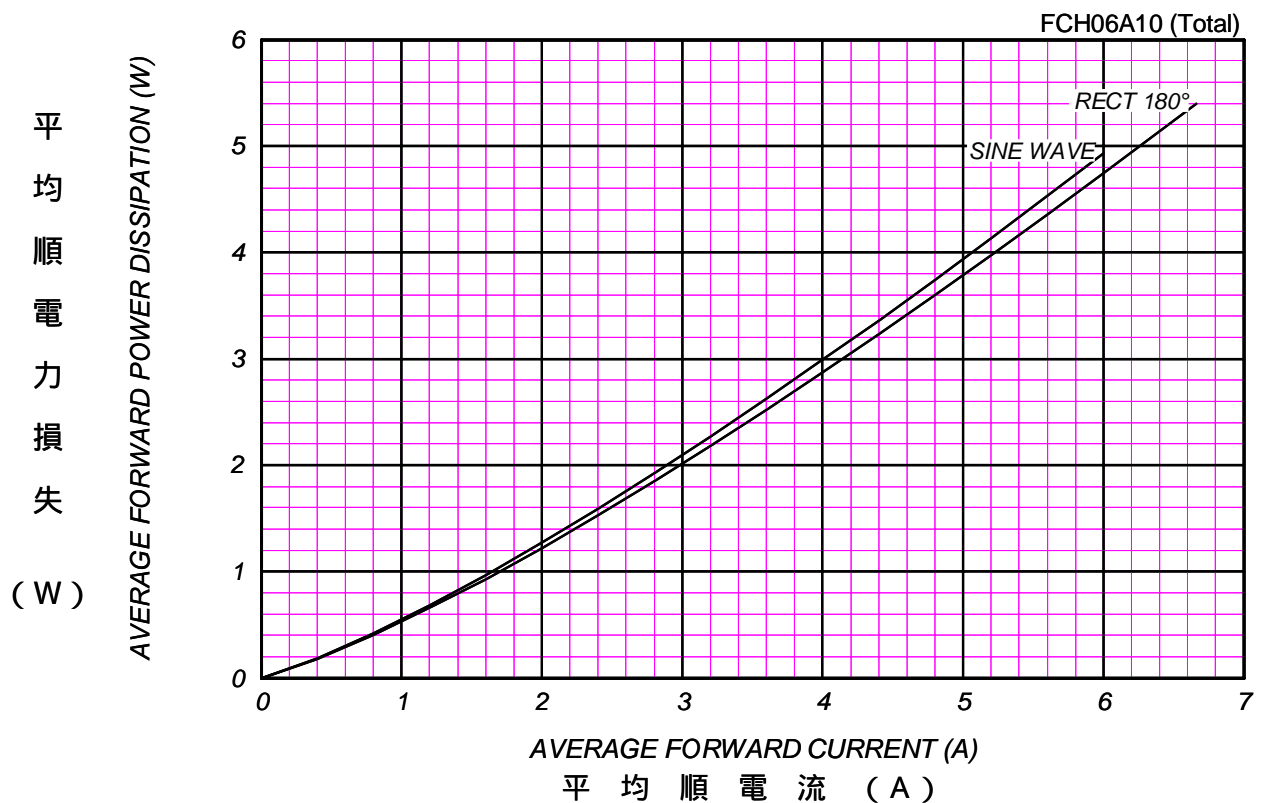
Center Tap



順電壓特性  
FORWARD CURRENT VS. VOLTAGE

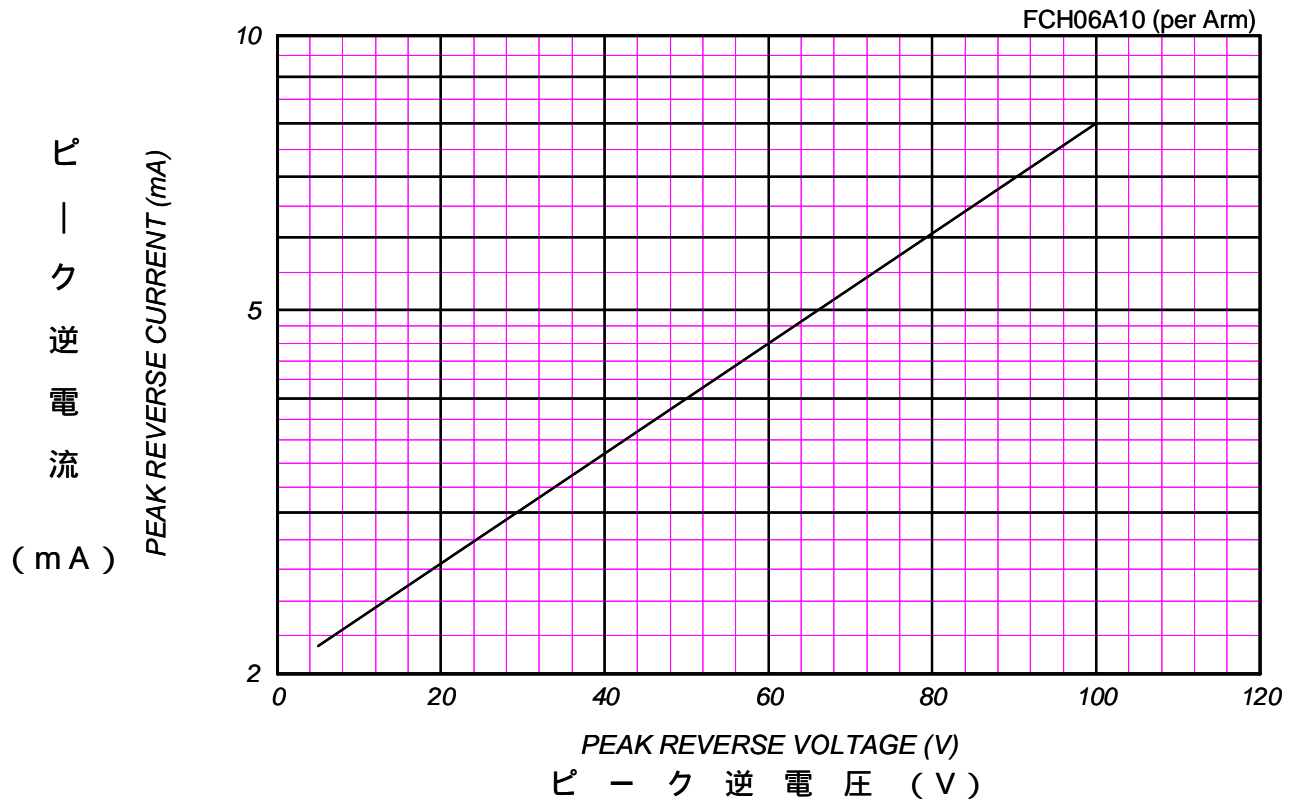


平均順電力損失特性  
AVERAGE FORWARD POWER DISSIPATION

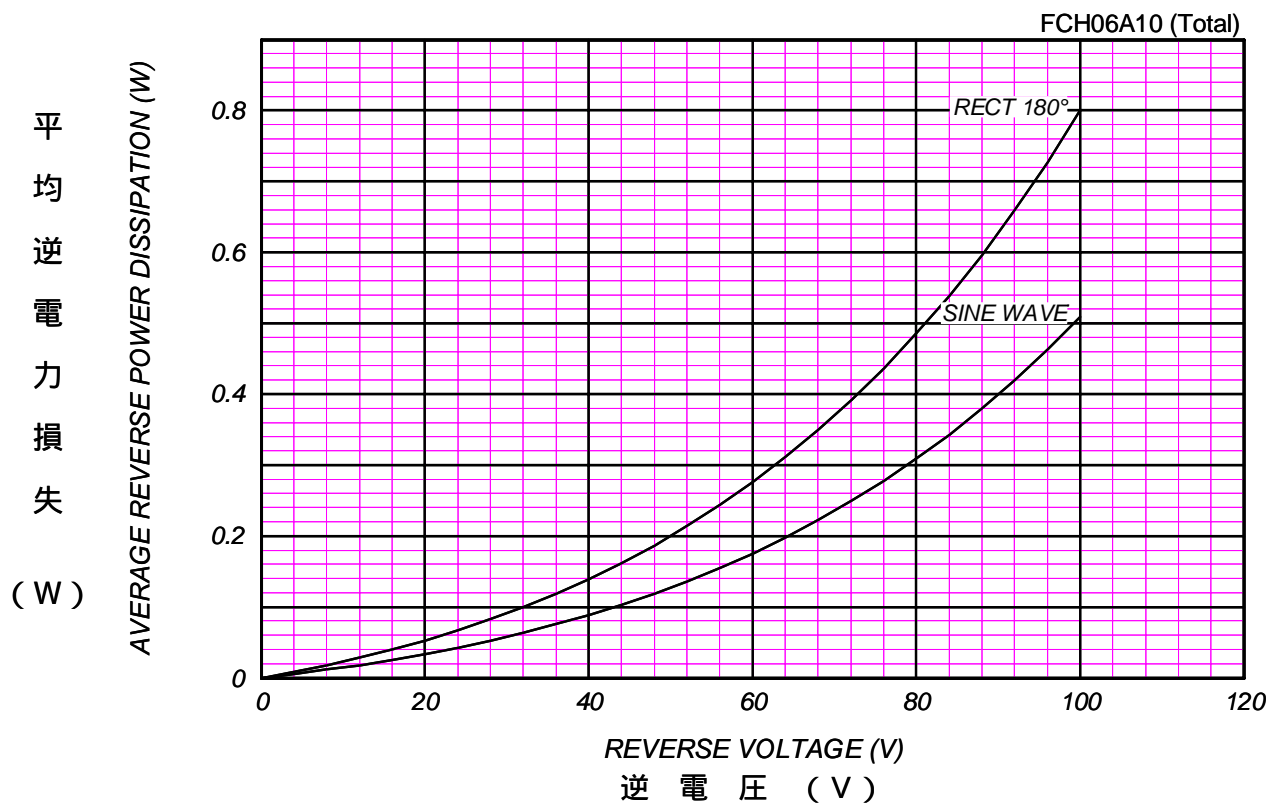


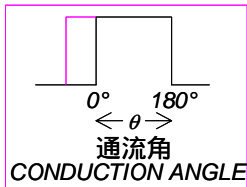
ピーク逆電流 - ピーク逆電圧特性  
 PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

T<sub>j</sub> = 150 °C



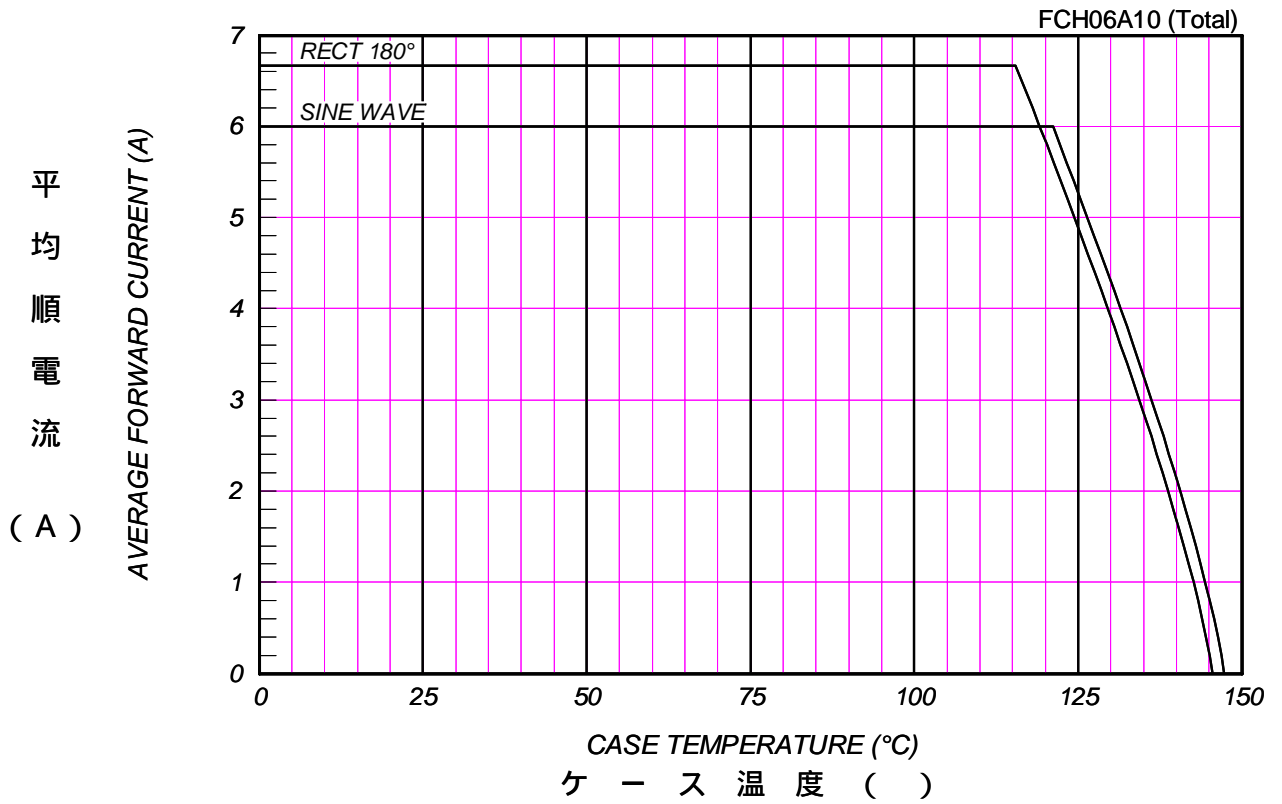
平均逆電力損失  
 AVERAGE REVERSE POWER DISSIPATION





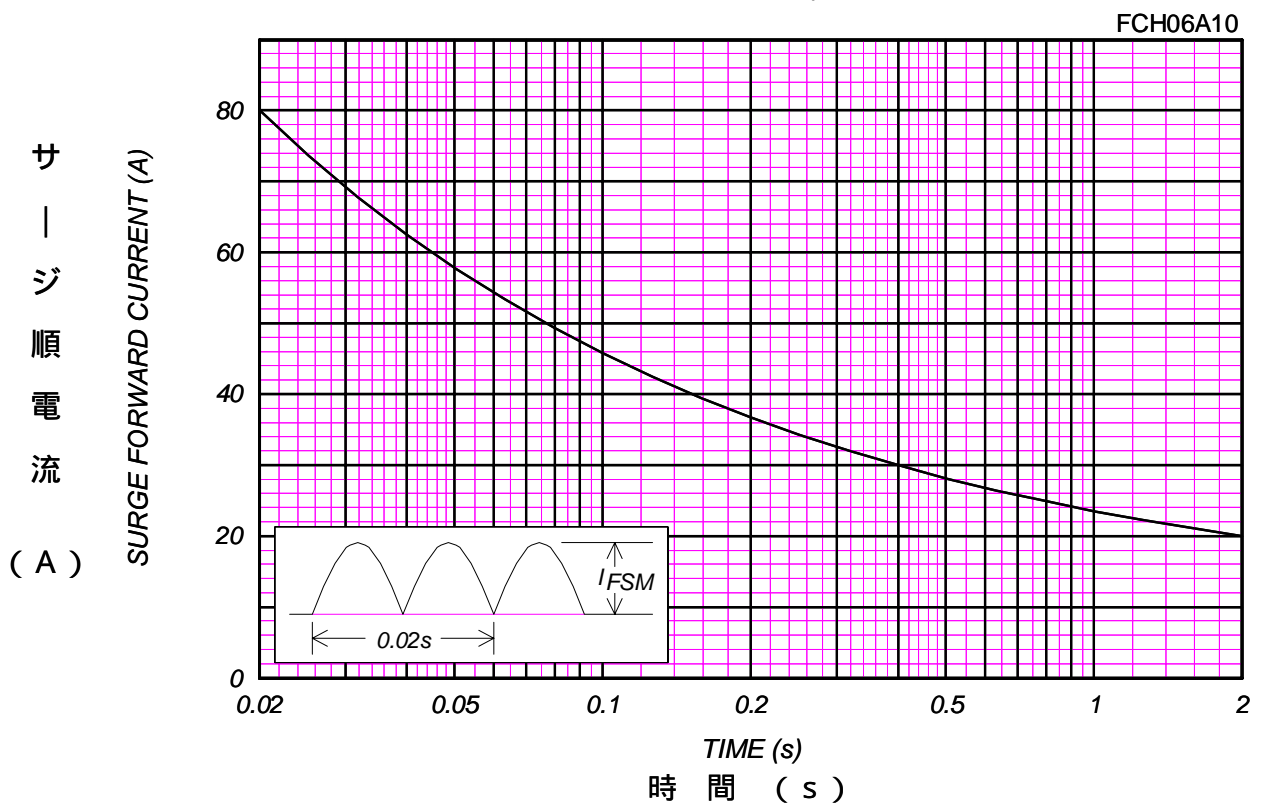
平均順電流 - ケース温度定格  
 AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM}=100V$



サージ順電流定格  
 SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load



接 合 容 量 特 性  
JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

$T_j=25^{\circ}\text{C}$ ,  $V_m=20\text{mV}_{\text{RMS}}$ ,  $f=100\text{kHz}$ , Typical Value

FCH06A10 (per Arm)

